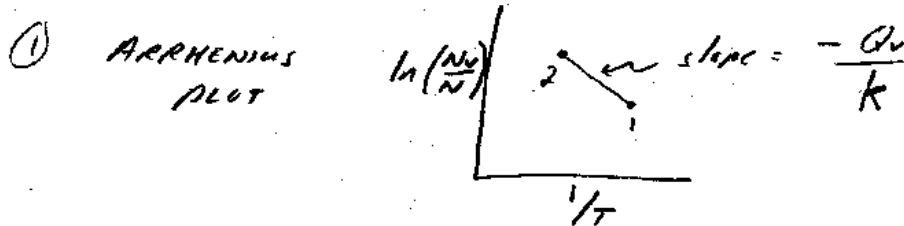


ENGR 240 HW #5

$$T_1 = 450^\circ\text{C} = 723\text{K}, \quad \left(\frac{N_v}{N}\right)_1 = 1.0 \times 10^{-6}$$

$$T_2 = 475^\circ\text{C} = 748\text{K}, \quad \left(\frac{N_v}{N}\right)_2 = 2.2 \times 10^{-6}$$

- could solve 2 ways:



OR

② 2 EQUATIONS, 2 UNKNOWNNS ...

$$\left(\frac{N_v}{N}\right)_2 = A_0 \exp\left(\frac{-Q_v}{kT_2}\right)$$

$$\left(\frac{N_v}{N}\right)_1 = A_0 \exp\left(\frac{-Q_v}{kT_1}\right)$$

→ divide: $\frac{(N_v/N)_2}{(N_v/N)_1} = \exp\left[\frac{-Q_v}{k}\left(\frac{1}{T_2} - \frac{1}{T_1}\right)\right]$

$$\frac{2.2}{1.0} = \exp\left[\frac{-Q_v}{k}\left(\frac{1}{748\text{K}} - \frac{1}{723\text{K}}\right)\right] \rightarrow \frac{Q_v}{k} = 17,000\text{K}$$

(Kelvin)

$$Q_v = 17,000 \text{ K} (1.38 \times 10^{-23} \text{ J/K}) = \boxed{2.3 \times 10^{-19} \text{ J}}$$

• Also, w/ $2.2 \times 10^{-6} = A_0 \exp\left(-\frac{17,000}{\frac{Q_v}{k}}\right)$, $A_0 = 16,000$

b) At $500^\circ\text{C} = 773 \text{ K}$,

$$\frac{N_v}{N} = 16,000 \exp\left(\frac{-17,000}{773}\right) = 4.5 \times 10^{-6}$$

OR

$$\boxed{4.5 \text{ out of } 1,000,000}$$

2) Unsteady-state Diffusion (semi-infinite slab)

$$D = 7.0 \times 10^{-17} \text{ m}^2/\text{s}$$

$$x = 1.0 \times 10^{-6} \text{ m}$$

$$C_s = 0.00100$$

$$C_0 = 0 \text{ (pure Si)}$$

$$C_x = 0.00035$$

$$a) \frac{C_x - C_0}{C_s - C_0} = \frac{0.00035}{0.00100} = 0.35$$

$$\downarrow$$

$$= 1 - \operatorname{erf}\left(\frac{x}{2\sqrt{Dt}}\right)$$

from hand-out (or table 5.1),

$$\frac{x}{2\sqrt{Dt}} = 0.65 = \frac{1 \times 10^{-6} \text{ m}}{2 \left(7.0 \times 10^{-17} \frac{\text{m}^2}{\text{s}} \cdot t\right)^{1/2}}$$

$$\downarrow$$

$$t = 8450 \text{ s}$$

(2 hr, 20 min)

b)

x (m)	$\frac{x}{2\sqrt{Dt}}$	$\frac{C_x - 0}{C_s - 0}$	C_x (mol. fract.) 6a
0.25×10^{-6}	0.16	0.80	0.00080
0.50×10^{-6}	0.33	0.63	0.00063
0.75×10^{-6}	0.49	0.48	0.00048

\uparrow
from handout

c) BASIS: 1 mole of ALLOY

$$0.00035 \text{ mol Ga} \left(\frac{69.72 \text{ g}}{\text{mol}} \right) = 0.024 \text{ g Ga}$$

$$0.99965 \text{ mol Si} \left(\frac{28.09 \text{ g}}{\text{mol}} \right) = 28.08 \text{ g Si}$$

$$\frac{0.024}{28.08 + 0.024} = 0.00085 \text{ wt. fract. Ga}$$

d) $D = D_0 \exp \left(\frac{-EA}{RT} \right)$

at 1100 °C (1373 K),

$$7.0 \times 10^{-17} \frac{\text{m}^2}{\text{s}} = D_0 \exp \left(\frac{-330,000 \text{ J/mol}}{8.314 \text{ J/mol} \cdot \text{K} (1373 \text{ K})} \right)$$

$$D_0 = 2.5 \times 10^{-4} \frac{\text{m}^2}{\text{s}}$$

so, solve for ...

$$5.0 \times 10^{-16} = 2.5 \times 10^{-4} \exp \left(\frac{-330,000}{8.314 T} \right)$$

$$T = 1473 \text{ K} = 1200 \text{ °C}$$